BLF573; **BLF573S**

HF / VHF power LDMOS transistor Rev. 4 — 1 September 2015



Product profile

1.1 General description

A 300 W LDMOS RF power transistor for broadcast applications and industrial, scientific and medical applications in the HF to 500 MHz band.

Table 1. **Production test information**

Mode of operation	f	V _{DS}	PL	Gp	η_{D}
	(MHz)	(V)	(W)	(dB)	(%)
CW	225	50	300	27.2	70

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- Typical CW performance at frequency of 225 MHz, a supply voltage of 50 V and an I_{Da} of 900 mA:
 - ◆ Average output power = 300 W
 - ◆ Power gain = 27.2 dB
 - ◆ Efficiency = 70 %
- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF and VHF band)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
BLF573 (S	OT502A)			
1	drain			,
2	gate			1
3	source	<u>[1]</u>		2 -
				3 sym112
BLF573S ((SOT502B)			<u> </u>
1	drain			4
2	gate		3	اً ا
3	source	<u>[1]</u>	2	2
				3 sym112
				Sylli112

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Packag	ge	
	Name	Description	Version
BLF573	-	flanged LDMOST ceramic package; 2 mounting holes; 2 leads	SOT502A
BLF573S	-	earless flanged LDMOST ceramic package, 2 leads	SOT502B

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	110	V
V_{GS}	gate-source voltage		-0.5	+11	V
I_D	drain current		-	42	Α
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	225	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Тур	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	T _{case} = 80 °C; P _L = 300 W	[1]	0.21	K/W

^[1] $R_{th(j-c)}$ is measured under RF conditions.

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6. Characteristics

Table 6. DC characteristics

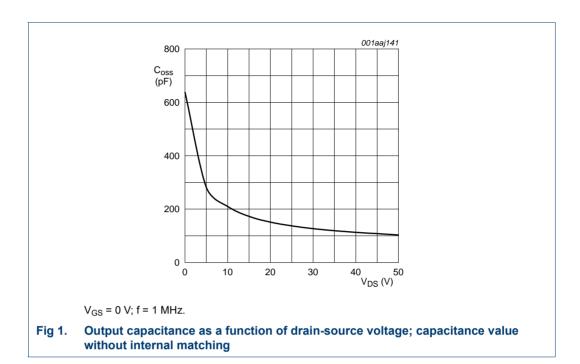
 $T_i = 25$ °C unless otherwise specified.

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS} \\$	drain-source breakdown voltage	V_{GS} = 0 V; I_{D} = 3.75 mA	110	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 375 mA	1.25	1.7	2.25	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 50 V; I_{D} = 900 mA	1.45	1.95	2.45	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}$	-	-	4.2	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	44	56	-	Α
I_{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	420	nA
9 _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 18.75 A	-	20	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 12.49 \text{ A}$	-	0.09	-	Ω
C _{rs}	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V};$ f = 1 MHz	-	2.3	-	pF
C _{iss}	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V};$ f = 1 MHz	-	300	-	pF
C _{oss}	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V};$ f = 1 MHz	-	103	-	pF

Table 7. RF characteristics

Mode of operation: CW; f = 225 MHz; RF performance at V_{DS} = 50 V; I_{Dq} = 900 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G_p	power gain	P _L = 300 W	26	27.2	28.4	dB
RLin	input return loss	P _L = 300 W	10	13	-	dB
η_{D}	drain efficiency	P _L = 300 W	67	70	-	%



6.1 Ruggedness in class-AB operation

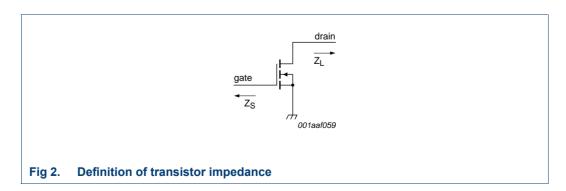
The BLF573 and BLF573S are capable of withstanding a load mismatch corresponding to VSWR = 13 : 1 through all phases under the following conditions: V_{DS} = 50 V; I_{Dq} = 900 mA; P_{L} = 300 W; f = 225 MHz.

7. Application information

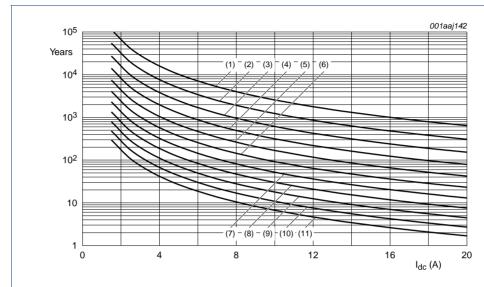
7.1 Impedance information

Table 8.Typical impedanceMeasured Z_S and Z_L test circuit impedances.

_			
f	Z _S	Z _L	
MHz	Ω	Ω	
225	0.7 + j2.0	1.95 + j2.0	



7.2 Reliability



TTF (0.1 % failure fraction).

- (1) $T_i = 100 \, ^{\circ}C$
- (2) $T_i = 110 \, ^{\circ}C$
- (3) $T_i = 120 \, ^{\circ}C$
- (4) $T_i = 130 \, ^{\circ}C$
- (5) $T_j = 140 \, ^{\circ}C$
- (6) $T_i = 150 \, ^{\circ}C$
- (7) $T_i = 160 \, ^{\circ}C$
- (8) $T_j = 170 \, ^{\circ}C$
- (9) $T_j = 180 \,^{\circ}\text{C}$ (10) $T_j = 190 \,^{\circ}\text{C}$
- (11) $T_i = 200 \,^{\circ}\text{C}$

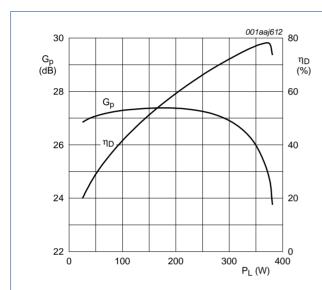
Fig 3. BLF573 and BLF573S electromigration (I_D, total device)

8. Test information

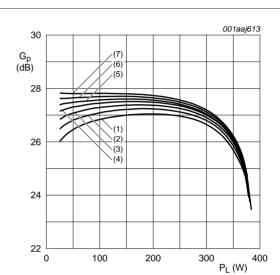
8.1 RF Performance

The following figures are measured in a class-AB production test circuit.

8.1.1 1-Tone CW



 $V_{DS} = 50 \text{ V}; I_{Dq} = 900 \text{ mA}; f = 225 \text{ MHz}.$

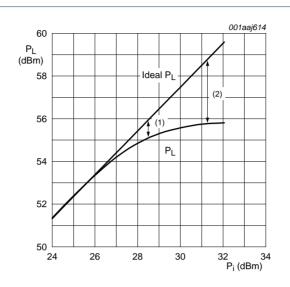


 $V_{DS} = 50 \text{ V}$; f = 225 MHz.

- (1) $I_{Dq} = 500 \text{ mA}$
- (2) $I_{Dq} = 700 \text{ mA}$
- (3) $I_{Dq} = 900 \text{ mA}$
- (4) $I_{Dq} = 1100 \text{ mA}$
- (5) $I_{Dq} = 1300 \text{ mA}$
- (6) $I_{Dq} = 1500 \text{ mA}$
- (7) $I_{Dq} = 1700 \text{ mA}$

Fig 4. Power gain and drain efficiency as functions of load power; typical values

Fig 5. Power gain as function of load power; typical values

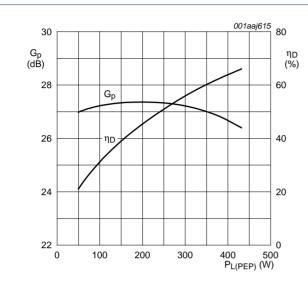


 V_{DS} = 50 V; I_{Dq} = 900 mA; f = 225 MHz.

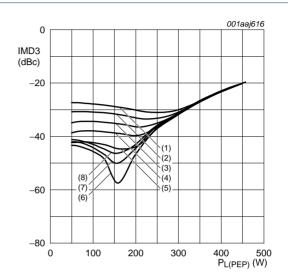
- (1) $P_{L(1dB)} = 55.2 \text{ dBm } (330 \text{ W})$
- (2) $P_{L(3dB)} = 55.8 \text{ dBm } (380 \text{ W})$

Fig 6. Load power as function of input power; typical values

8.1.2 2-Tone CW



 V_{DS} = 50 V; I_{Dq} = 900 mA; f_1 = 224.95 MHz; f_2 = 225.05 MHz.



 $V_{DS} = 50 \text{ V}$; $f_1 = 224.95 \text{ MHz}$; $f_2 = 225.05 \text{ MHz}$.

- (1) $I_{Dq} = 500 \text{ mA}$
- (2) $I_{Dq} = 700 \text{ mA}$
- (3) $I_{Dq} = 900 \text{ mA}$
- (4) $I_{Dq} = 1100 \text{ mA}$
- (5) $I_{Dq} = 1300 \text{ mA}$ (6) $I_{Dq} = 1500 \text{ mA}$
- (7) $I_{Dq} = 1700 \text{ mA}$
- () bq ---
- (8) $I_{Dq} = 1800 \text{ mA}$

Fig 7. Power gain and drain efficiency as functions of peak envelope load power; typical values

Fig 8. Third order intermodulation distortion as a function of peak envelope load power; typical values

8.2 Test circuit

Table 9. List of components

For production test circuit, see Figure 9 and Figure 10.

Printed-Circuit Board (PCB): Rogers 5880; $\varepsilon_r = 2.2$ F/m; height = 0.79 mm; Cu (top/bottom metallization); thickness copper plating = 35 μ m.

Component	Description	Value	Remarks
B1	ferrite SMD bead	100 Ω; 100 MHz	Ferroxcube BDS3/3/8.9-4S2 or equivalent
C1, C18	multilayer ceramic chip capacitor	100 pF	<u>[1]</u>
C2	multilayer ceramic chip capacitor	39 pF	[1]
C3, C4	multilayer ceramic chip capacitor	180 pF	<u>[1]</u>
C5, C6, C7	multilayer ceramic chip capacitor	220 pF	<u>[1]</u>
C8, C20	multilayer ceramic chip capacitor	1 nF	<u>[1]</u>
C9	multilayer ceramic chip capacitor	4.7 μF	TDK C4532X7R1E475MT020U or equivalent
C10	multilayer ceramic chip capacitor	30 pF	<u>[1]</u>
C11, C12, C13	multilayer ceramic chip capacitor	51 pF	[1]
C14	multilayer ceramic chip capacitor	43 pF	<u>[1]</u>

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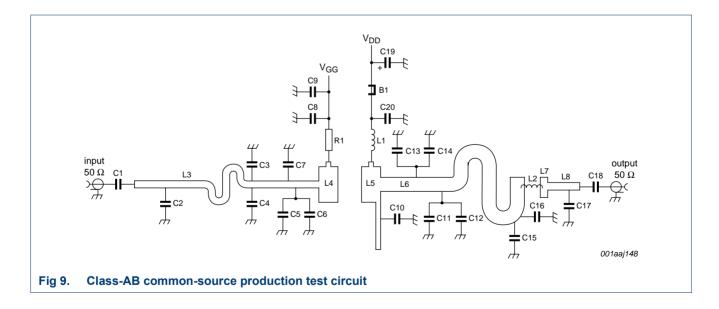
Table 9. List of components ... continued

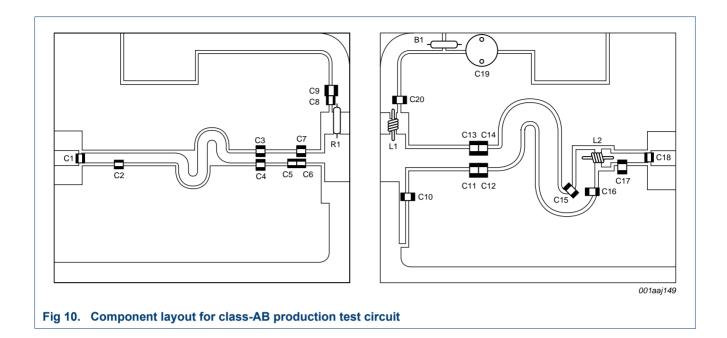
For production test circuit, see Figure 9 and Figure 10.

Printed-Circuit Board (PCB): Rogers 5880; $\varepsilon_r = 2.2$ F/m; height = 0.79 mm; Cu (top/bottom metallization); thickness copper plating = 35 μ m.

Component	Description	Value	Remarks
C15	multilayer ceramic chip capacitor	33 pF	Ш
C16	multilayer ceramic chip capacitor	36 pF	Ш
C17	multilayer ceramic chip capacitor	16 pF	Ш
C19	electrolytic capacitor	220 μF; 63 V	
L1	2 turns enamelled copper wire	D = 3 mm; d = 1 mm; length = 2 mm; leads = 2 × 6 mm	
L2	4 turns enamelled copper wire	D = 2 mm; d = 1 mm; length = 13 mm; leads = 2 × 5 mm	
L3	stripline	-	$(L \times W)$ 96 mm \times 3 mm
L4, L5	stripline	-	(L \times W) 15 mm \times 8 mm
L6	stripline	-	(L \times W) 105 mm \times 6 mm
L7	stripline	-	$(L \times W)$ 3 mm \times 6 mm
L8	stripline	-	(L \times W) 12 mm \times 6 mm
R1	metal film resistor	100 Ω; 0.6 W	

[1] American Technical Ceramics type 100B or capacitor of same quality.





9. Package outline

Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A

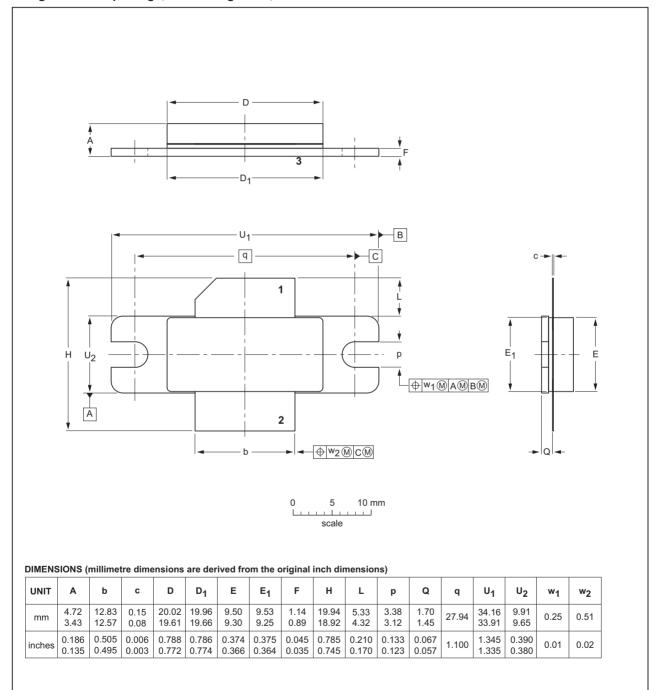


Fig 11. Package outline SOT502A

IEC

OUTLINE

VERSION

SOT502A

JEITA

REFERENCES

JEDEC

ISSUE DATE

03-01-10

12-05-02

EUROPEAN

PROJECTION

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Earless flanged ceramic package; 2 leads

SOT502B

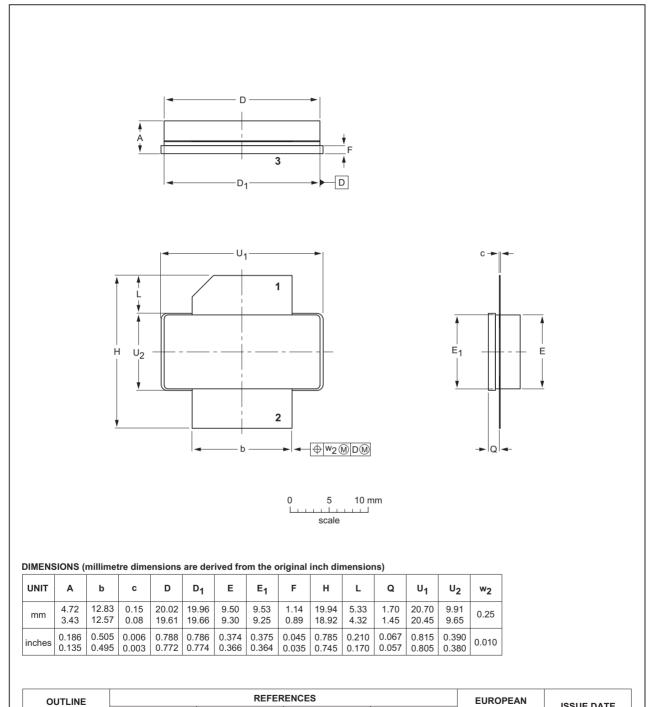


Fig 12. Package outline SOT502B

IEC

JEDEC

VERSION

SOT502B

JEITA

PROJECTION

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ISSUE DATE

07-05-09

12-05-02

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
CW	Continuous Wave
EDGE	Enhanced Data rates for GSM Evolution
GSM	Global System for Mobile communications
HF	High Frequency
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
RF	Radio Frequency
SMD	Surface Mount Device
TTF	Time To Failure
VHF	Very High Frequency
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BLF573_BLF573S#4	20150901	Product data sheet	-	BLF573_BLF573S v.3		
Modifications:	guidelines of A	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 				
BLF573_BLF573S v.3	20100708	Product data sheet	-	BLF573S v.2		
BLF573S v.2	20090217	Product data sheet	-	BLF573S v.1		
BLF573S v.1	20081208	Preliminary data sheet	-	-		

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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